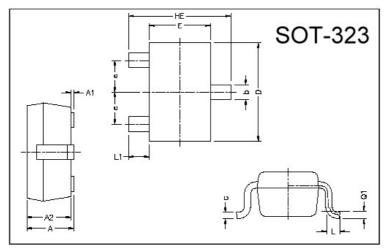
# **GS420SD**

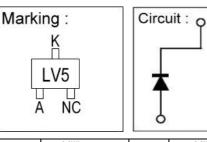
# SURFACE MOUNT, SCHOTTKY BARRIER DIODE **VOLTAGE 40V, CURRENT 0.1A**

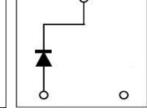
## Description

The GS420SD is designed for low power rectification.

# **Package Dimensions**







ĺ	REF.	Millimeter		REF.	Millimeter		
		Min.	Max.	nLI.	Min.	Max.	
	А	0.80	1.10	L1	0.42	REF.	
	A1	0	0.10	L	0.15	0.35	
	A2	0.80	1.00	b	0.25	0.40	
	D	1.80	2.20	С	0.10	0.25	
	Е	1.15	1.35	е	0.65	REF. BSC.	
	HE	1.80	2.40	Q1	0.15		

# Absolute Maximum Ratings at TA = 25℃

Parameter	Symbol	Ratings	Unit	
Junction Temperature	Tj	+125	°C	
Storage Temperature	Tstg	-40 ~ +125	°C	
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	40	V	
Maximum RMS Voltage	V <sub>RMS</sub>	28	V	
Maximum DC Blocking Voltage	V <sub>DC</sub>	40	V	
Peak Forward Surge Current at 8.3mSec single half sine-wave	I <sub>FSM</sub>	1.0	A	
Typical Junction Capacitance between Terminal (Note 1)	CJ	6.0	pF	
Maximum Average Forward Rectified Current	lo	0.1	A	
Total Power Dissipation	PD	225	mW	

## Electrical Characteristics (at TA = 25°C unless otherwise noted)

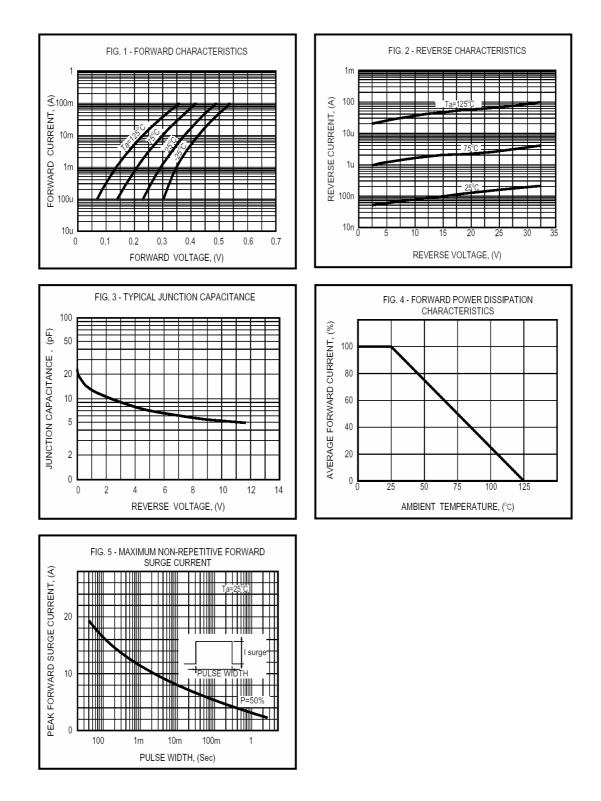
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Reverse Breakdown Voltage	V(BR)R	40	-	-	V	IR=100µA
Maximum Instantaneous Forward Voltage	VF	-	-	450	mV	IF=10mA
Maximum Average Reverse Current	lr	-	-	1.0	uA	VR=10V

Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 10 volts.

2. ESD sensitive product handling required.

# GTM

## **Characteristics Curve**



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